



NSVBSP19AT1G Information



For Reference Only

Part Number NSVBSP19AT1G Manufacturer ON Semiconductor

Category Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single

Description TRANS NPN 350V 0.1A SOT223

Package TO-261-4, TO-261AA

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









NSVBSP19AT1G Specifications

Manufacturer Part Number	NSVBSP19AT1G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-261-4, TO-261AA
Series	-
Transistor Type	NPN
Current - Collector (Ic) (Max)	100mA
Voltage - Collector Emitter Breakdown (Max)	350V
Vce Saturation (Max) @ Ib, Ic	500mV @ 4mA, 50mA
Current - Collector Cutoff (Max)	20nA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	40 @ 20mA, 10V
Power - Max	800mW
Frequency - Transition	70MHz
Operating Temperature	-65°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-261-4, TO-261AA
Supplier Device Package	SOT-223 (TO-261)
	Report errors?

NSVBSP19AT1G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

NSVBSP19AT1G Payment Methods



















NSVBSP19AT1G Shipping Methods













If you have any question about NSVBSP19AT1G, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com